





ZXCT1080Q/ZXCT1081Q

AUTOMOTIVE GRADE 60/40V HIGH-SIDE CURRENT MONITOR

Description

The ZXCT1080Q and ZXCT1081Q are high side current sense monitors with a voltage output and a fixed gain of 10. Using this device eliminates the need to disrupt the ground plane when sensing a load current.

The wide input voltage range of 60V and 40V, respectively, down to as low as 3V make it suitable for a range of automotive applications with 60V and 40V load dump withstand capabilities.

The separate supply pin $(V_{\rm CC})$ allows the device to continue functioning under short circuit conditions.

The ZXCT1080Q and ZXCT1081Q have an extended ambient operating temperature range of -40°C to 125°C enabling it to be used in a wide range of automotive applications including.

The ZXCT1080Q and ZXCT1081Q have been qualified to AEC-Q100 Grade 1 and are Automotive Grade supporting PPAPs.

Features

- Accurate high-side current sensing
 - ZXCT1080Q: 3V to 60V continuous high side voltage
 - ZXCT1081Q: 3V to 40V continuous high side voltage
- -40°C to +125°C temperature range
- Output voltage scaling x10
- 4.5V to 12V V_{CC} range
- Low quiescent current:
 - 80µA supply pin
 - 27µA I_{S+}
- Green Molding in SOT25
 - Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
 - Halogen and Antimony Free. "Green" Device (Note 3)
- Automotive Grade

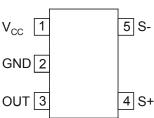
Notes:

- Qualified to AEC-Q100 Standards for High Reliability
- PPAP Capable (Note 4)

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q100 qualified and are PPAP capable. Automotive, AEC-Q100 and standard products are electrically and thermally the same, except where specified. For more information, please refer to http://www.diodes.com/quality/product_compliance_definitions/.

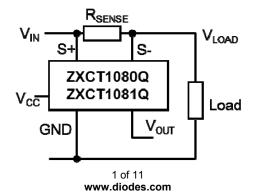
Pin Assignments



Applications

- Automotive current measurement
- Battery management
- Over-current measurement

Typical Application Circuit





ZXCT1080Q/ZXCT1081Q

Pin Descriptions

Pin	Name	Function							
		Common	ZXCT1080Q	ZXCT1081Q					
1	Vcc	This is the analogue supply and provides power to internal circuitry	_	_					
2	GND	Ground pin — —		_					
3	OUT	Output voltage pin. NMOS source follower with 20µA bias to ground — — —		_					
4	S+		Input range from 60V Input range from 40\						
5	S-	This is the negative input of the current monitor.	down to 3V down to 3V						

Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

	Parameter	•	Rating	Unit	
Continuous valt	togo on C. and C.	ZXCT1080Q (Note 5)	-0.6 to 65	V	
Continuous voit	tage on S- and S+	ZXCT1081Q (Note 5)	-0.6 to 45	¬	
Transient voltag	ge on S- and S+	ZXCT1081Q (Note 5)	-0.6 to 65	V	
Voltage on all o	other pins		-0.6 to +14	V	
Differential sens	se voltage, V _{SENSE} (Note 6)		800	mV	
Operating temp	perature		-40 to +125	°C	
Storage Tempe	erature	-55 to +150	°C		
Maximum Junc	tion Temperature	+125	°C		
Dookogo Dowo	r Dissipation (Note 7)	300	mW		
Package Power	Dissipation (Note 7)	(@ T _A = +25°C)	IIIVV		
		ESD Ratings			
HBM ESD	Human Body Model	1000	V		
MM ESD	Machine Model	150	V		
CDM ESD Charged Device Model			TBD	V	

Caution: Stresses greater than the 'Absolute Maximum Ratings' specified above, may cause permanent damage to the device. These are stress ratings only; functional operation of the device at conditions between maximum recommended operating conditions and absolute maximum ratings is not implied. Device reliability may be affected by exposure to absolute maximum rating conditions for extended periods of time.

Semiconductor devices are ESD sensitive and may be damaged by exposure to ESD events. Suitable ESD precautions should be taken when handling and transporting these devices.

- Notes: 5. ZXCT1080 has a maximum transient and continuous voltage of 65V on the S+ and S- pin. The ZXCT1081 has a maximum continuous of 45V, it however can withstand transient up to 65V.
 - 6. V_{SENSE} is defined as the differential voltage between S+ and S- pins
 - 7. Assumes θ_{JA} = 420°C/W

Recommended Operating Conditions

Symbol	Parameter	Min	Max	Units	
\/	Common mode Conse Linnut Donge	ZXCT1080Q	3	60	V
V _{IN}	Common-mode Sense+ Input Range	ZXCT1081Q		40	
Vcc	Supply Voltage Range	4.5	12	V	
V _{SENSE}	Differential Sense Input Voltage Range	0	0.15	V	
V _{OUT}	Ouput Voltage Range (Note 8)	0	1.5	V	
T _A	Ambient Temperature Range	-40	+125	°C	

8. Based on 10x V_{SENSE} Note:



ZXCT1080Q/ZXCT1081Q

Electrical Characteristics (@ $V_{IN} = V_{S+} = 12V$, $V_{CC} = 5V$, V_{SENSE} (Note 6) = 100 mV, $T_A = +25 ^{\circ}\text{C}$, unless otherwise specified.)

Symbol	Parameter	Conditions		T _A	Min	Тур	Max	Units
Icc	V _{CC} Supply Current	V _{CC} = 12V, V _{SENSE} = 0V	ZXCT1080Q ZXCT1081Q	+25°C	40	80	120 µA	μA
			ZXCT1080Q	Full range	1	_	145	
		V _{SENSE} = 0V	ZXCT1080Q	+25°C	15	27	42	
I _{S+}	S+ Input Current		ZXCT1081Q		15	30	60	μA
			ZXCT1080Q	Full range		_	60	
I-	S- Input Current		ZXCT1080Q	+25°C	15	40	80	nA
I _{S-}	3- input Guilent	V _{SENSE} = 0V	ZXCT1081Q	+25-0	10	40	OU NA	IIA
V _{O(0)}	Zero V _{SENSE} error (Note 9)	VSENSE - UV	ZXCT1080Q ZXCT1081Q	+25°C	0	_	35	mV
	Output Offset Voltage (Note 10)	V _{SENSE} = 10mV	ZXCT1080Q	+25°C	-25		+25 +30 mV +55	
V _{O(10)}			ZXCT1081Q		-30	_		mV
, ,			ZXCT1080Q	Full range	-55	_		
	$\Delta V_{ m OUT}/\Delta V_{ m SENSE}$	V _{SENSE} = 10mV to 150mV	ZXCT1080Q	+25°C	9.9	10	10.1	V/V
Gain			ZXCT1081Q		9.95	10	10.05	
			ZXCT1080Q	Full range	9.8	_	10.2	
V _{OUT} TC	V _{OUT} variation with temperature	_		_	_	30	_	ppm/°C
Acc	Total output error	_		_	-3	_	3	%
I _{OH}	Output Source Current	$\Delta V_{OUT} = -30 Mv$		_	_	1	_	mA
I _{OL}	Output Sink Current	$\Delta V_{OUT} = +30 \text{mV}$		_	_	20	_	μΑ
PSRR	V _{CC} Supply Rejection Ration	V _{CC} = 4	.5V to 12V	_	54	60	_	dB
01.155		V _{S+} = 60V to 3V ZXCT1080Q			68	80		
CMRR	Common-Mode Sense Rejection Ratio	V _{S+} = 40V to 3 ^v	V ZXCT1081Q	_	60	75	_	dB
BW	-3dB small signal bandwidth	V _{SENSE (AC)} = 10mVpp		_	_	500	_	kHz

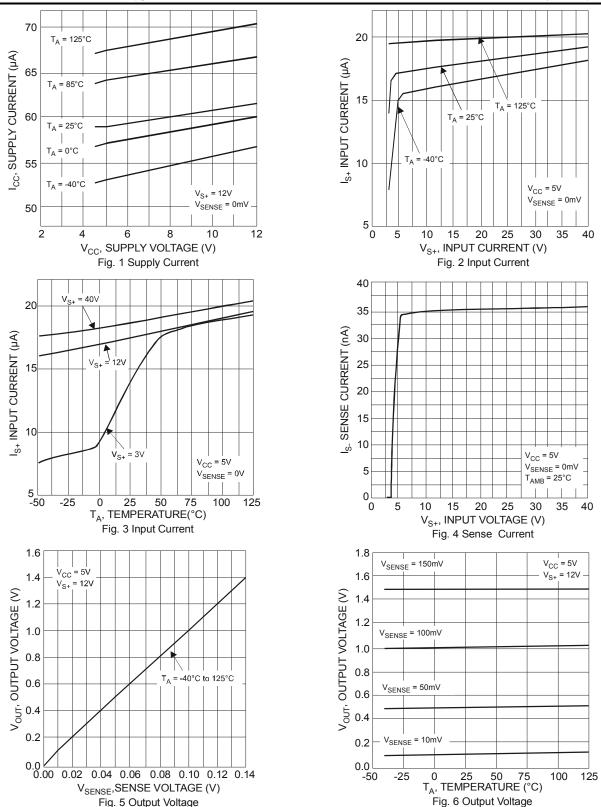
Notes: 6. V_{SENSE} = "V_{S-}" - "V_{S-}" 9. The ZXCT1080Q/81Q operates from a positive power rail and the internal voltage-current converter current flow is unidirectional; these result in the output offset voltage for V_{SENSE} = 0V always being positive.

For V_{SENSE} > 10mV, the internal voltage-current converter is fully linear. This enables a true offset to be defined and used. V_{O(10)} is expressed as the variance about an output voltage of 100mV>.



ZXCT1080Q/ ZXCT1081Q

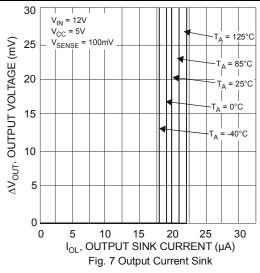
Typical Characteristics (@ V_{IN} = 12V, V_{CC} = 5V, V_{SENSE+} = 12V, V_{SENSE} = 100mV, T_A = +25°C, unless otherwise specified.)

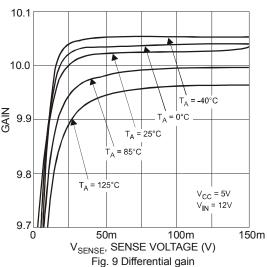


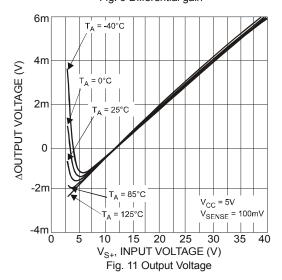


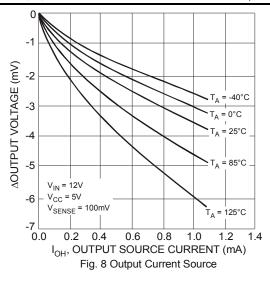
ZXCT1080Q/ ZXCT1081Q

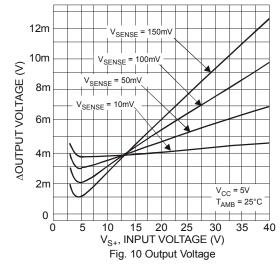
$\textbf{Typical Characteristics} \text{ (cont.) } (\textcircled{@} \ V_{\text{IN}} = 12 \text{V}, \ V_{\text{CC}} = 5 \text{V}, \ V_{\text{SENSE+}} = 12 \text{V}, \ V_{\text{SENSE}} = 100 \text{mV}, \ T_{\text{A}} = +25 ^{\circ}\text{C}, \ \text{unless otherwise specified.) }$





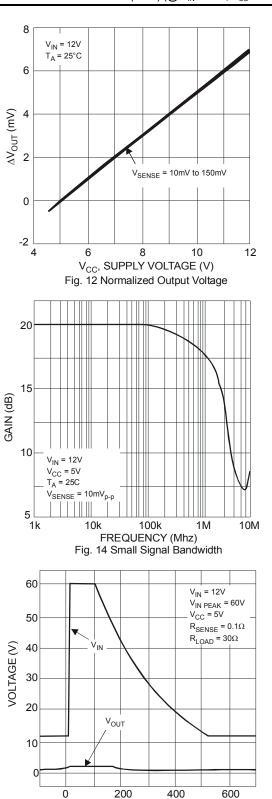






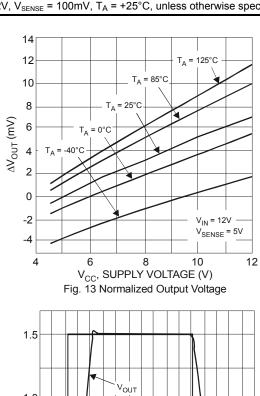


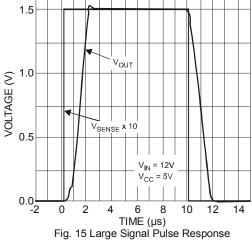
Typical Characteristics (cont.) (@ V_{IN} = 12V, V_{CC} = 5V, V_{SENSE+} = 12V, V_{SENSE} = 100mV, T_A = +25°C, unless otherwise specified.)

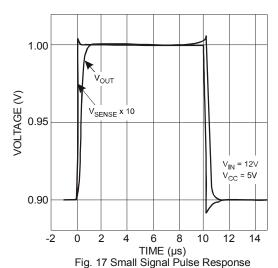


TIME (ms)

Fig. 16 Load Dump Waveform

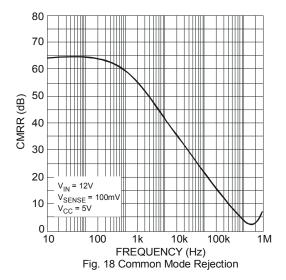


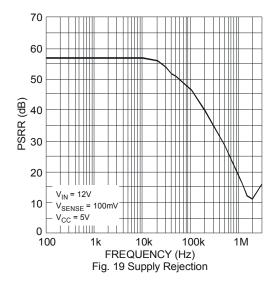






 $\textbf{Typical Characteristics} \ \, \text{(cont.)} \ \, (\textcircled{@} \ \, \text{V}_{\text{IN}} = 12 \text{V}, \ \, \text{V}_{\text{CC}} = 5 \text{V}, \ \, \text{V}_{\text{SENSE+}} = 12 \text{V}, \ \, \text{V}_{\text{SENSE}} = 100 \text{mV}, \ \, \text{T}_{\text{A}} = +25 ^{\circ}\text{C}, \ \, \text{unless otherwise specified.)}$







Application Information

The ZXCT1080Q and ZXCT1081Q have been designed to allow them to operate with 5V supply rails while sensing common mode signals up to 60V and 40V respectively. This makes it well suited to a wide range of current measuring/monitoring applications that require the interface to 5V systems while sensing much higher voltages.

To allow this its V_{CC} pin can be used independently of S+.

Figure 20 shows the basic configuration of the ZXCT1080Q and ZXCT1081Q.

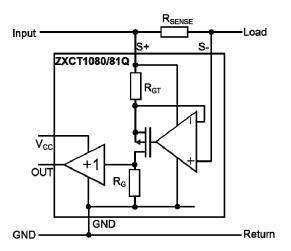


Fig. 20 Typical Configuration of ZXCT1080Q/81Q

 $Load\ current\ from\ the\ input\ is\ drawn\ through\ R_{SENSE}\ developing\ a\ voltage\ V_{SENSE}\ across\ the\ inputs\ of\ the\ ZXCT1080Q/81Q.$

The internal amplifier forces V_{SENSE} across internal resistance R_{GT} causing a current to flow through MOSFET M1. This current is then converted to a voltage by R_{G} . A ratio of 10:1 between R_{G} and R_{GT} creates the fixed gain of 10. The output is then buffered by the unity gain buffer.

The gain equation of the ZXCT1080Q and ZXCT1081Q is:

$$V_{OUT} = I_L R_{SENSE} \frac{R_G}{R_{GT}} \times 1 = I_L x R_{SENSE} \times 10$$

The maximum recommended differential input voltage, V_{SENSE} , is 150mV; it will however withstand voltages up to 800mV. This can be increased further by the inclusion of a resistor, R_{LIM} , between S- pin and the load (see figure 21); typical value is of the order of 10k.

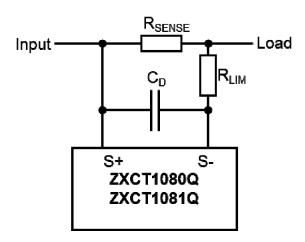


Fig. 21 Protection/Error Sources for ZXCT1080

Capacitor C_D provides high frequency transient decoupling when used with R_{LIM}; typical values are of the order 10pF.



Application Information (cont.)

For best performance R_{SENSE} should be connected as close to the S+ (and SENSE) pins; minimizing any series resistance with R_{SENSE}.

When choosing appropriate values for R_{SENSE} a compromise must be reached between in-line signal loss (including potential power dissipation effects) and small signal accuracy.

Higher values for R_{SENSE} gives better accuracy at low load currents by reducing the inaccuracies due to internal offsets. For best operation the ZXCT1080Q/81Q has been designed to operate with V_{SENSE} of the order of 50mV to 150mV.

Current monitors' basic configuration is that of a unipolar voltage to current to voltage converter powered from a single supply rail. The internal amplifier at the heart of the current monitor may well have a bipolar offset voltage but the output cannot go negative; this results in current monitors saturating at very low sense voltages.

As a result of this phenomenon the ZXCT1080Q/81Q has been specified to operate in a linear manner over a V_{SENSE} range of 10mV to 150mV range, however it will still be monotonic down to V_{SENSE} of 0V.

It is for this very reason that Diodes has specified an input offset voltage ($V_{O(10)}$) at 10mV. The output voltage for any V_{SENSE} voltage from 10mV to 150mV can be calculated as follows:

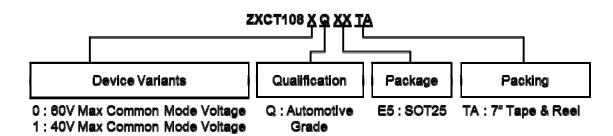
$$V_{OUT} = (V_{SENSE}) \times G + V_{(10)}$$

Alternatively the load current can be expressed as:

$$I_{L} = \frac{\left(V_{OUT} - V_{O(10)}\right)}{GxRsense}$$

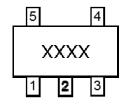


Ordering Information



Order Reference	Package	e Package Code	Identification Code	Packing: 7" Tape and Reel			Qualification Grade
Order Reference	Package			Quantity	Tape Width	Part Number Suffix	Qualification Grade
ZXCT1080QE5TA	SOT25	E5	1080	3000	8	TA	Automotive Grade
ZXCT1081QE5TA	SOT25	E5	1081	3000	8	TA	Automotive Grade

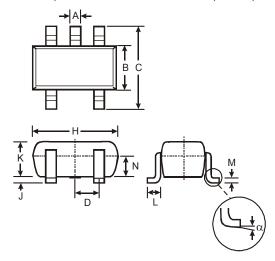
Marking Information



XXXX: Identification code

Package Outline Dimensions (All Dimensions in mm)

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.

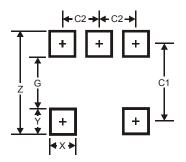


SOT25						
Dim	Min	Max	Тур			
Α	0.35	0.50	0.38			
В	1.50	1.70	1.60			
С	2.70	3.00	2.80			
D	D —		0.95			
Н	2.90	3.10	3.00			
7	0.013	0.10	0.05			
K	1.00	1.30	1.10			
L	0.35	0.55	0.40			
М	0.10	0.20	0.15			
N	0.70	0.80	0.75			
α	8°	_				
All Dimensions in mm						



Suggested Pad Layout (All Dimensions in mm)

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for latest version.



Dimensions	Value (in mm)
Z	3.20
G	1.60
Х	0.55
Υ	0.80
C1	2.40
C2	0.95

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